

SCDS181 - FEBRUARY 2005

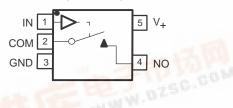
Description

The TS5A4596 is a single-pole single-throw (SPST) analog switch that is designed to operate from 2 V to 5 V. This device can handle both digital and analog signals, and signals up to V_{+} (peak) can be transmitted in either direction.

Applications

- Sample-and-Hold Circuit
- Battery-Powered Equipment
- Audio and Video Signal Routing
- Communication Circuits

SOT-23 OR SC-70 PACKAGE (TOP VIEW)



FUNCTION TABLE

IN	NO TO COM, COM TO NO
L	OFF
Н	ON

Features

- Low ON-State Resistance (8 Ω)
- ON-State Resistance Flatness (1.5 Ω)
- Control Inputs Are 5.5-V Tolerant
- Low Charge Injection (5 pC Max)
- 450-MHz –3-dB Bandwidth at 25°C
- Low Total Harmonic Distortion (THD) (0.04%)
- 2-V to 5.5-V Single-Supply Operation
- -85-dB OFF-Isolation at 1 MHz
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- 0.5-nA Max OFF Leakage
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- TTL/CMOS-Logic Compatible

Summary of Characteristics

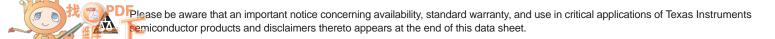
 $V_{+} = 5 \text{ V}, T_{A} = 25^{\circ}\text{C}$

Configuration	Single Pole Single Throw (SPST)
Number of channels	1
ON-state resistance (ron)	8 Ω
ON-state resistance flatness (ron(flat))	1.5 Ω
Turn-on/turn-off time (ton/toff)	17 ns/14 ns
Charge injection (Q _C)	5 pC
Bandwidth (BW)	450 MHz
OFF isolation (OISO)	–85 dB at 1 MHz
Total harmonic distortion (THD)	0.04%
Leakagecurrent(lCOM(OFF)/INO(OFF))	±0.5 nA
Power-supply current (I+)	0.25 μΑ
Package option	5-pin SOT-23 or SC-70

ORDERING INFORMATION

TA	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING(2)
4000 1- 0500	SOT (SOT-23) – DBV	Tape and reel	TS5A4596DBVR	JSC_
-40°C to 85°C	SOT (SC-70) - DCK	Tape and reel	TS5A4596DCKR	JU_

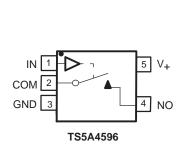
(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.
(2) DBV/DCK: The actual top-side marking has one additional character that designates the assembly/test site.

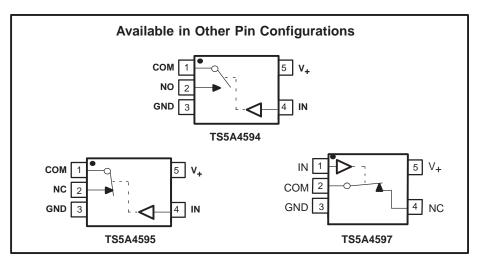




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Pin Configurations





Absolute Minimum and Maximum Ratings(1)(2)

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V ₊	Supply voltage range(3)		-0.3	6	V
V _{NO}	Analog voltage range(3)(4)		-0.3	V ₊ + 0.3	V
ΙK	Analog port diode current	V _{NO} , V _{COM} < 0	-50		mA
I _{NO} I _{COM}	On-state switch current	V_{NO} , $V_{COM} = 0$ to V_{+}	-20	20	mA
I _{NO} I _{COM}	On-state switch current (pulsed at 1 ms, 10% duty cycle)	V_{NO} , $V_{COM} = 0$ to V_{+}	-40	40	mA
VI	Digital input voltage range(3)(4)		-0.3	6	V
lik	Digital input clamp current	V _I < 0	-50		mA
1+	Continuous current through V ₊			100	mA
IGND	Continuous current through GND		-100		mA
_	Back and the small investors (5)	DBV package	2		2000
θJΑ	Package thermal impedance ⁽⁵⁾	DCK package		252	°C/W
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.

- (2) The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum
- (3) All voltages are with respect to ground, unless otherwise specified.
- (4) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
- (5) The package thermal impedance is calculated in accordance with JESD 51-7.



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Electrical Characteristics for 5-V Supply⁽¹⁾ $V_+ = 4.5 \text{ V}$ to 5.5 V, $T_A = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	TA	٧+	MIN	TYP	MAX	UNIT	
Analog Switch					•				
Analog signal range	V _{COM} , V _{NO}					0		٧+	V
ON-state resistance	r _{on}	V _{NO} = 3.5 V, I _{COM} = 10 mA,	Switch ON, See Figure 13	25°C Full	4.5 V		5	10	Ω
ON-state resistance flatness	ron(flat)	V _{NO} = 1.5 V, 2.5 V, 3.5 V, I _{COM} = 10 mA,	Switch ON, See Figure 13	25°C Full	4.5 V		0.5	1.5	Ω
NO OFF leakage current	INO(OFF)	V _{NO} = 1 V, V _{COM} = 4.5 V, or V _{NO} = 4.5 V, V _{COM} = 1 V,	Switch OFF, See Figure 14	25°C Full	5.5 V	-0.5 -5	0.01	0.5	nA
COM OFF leakage	ICOM(OFF)	V _{COM} = 1 V, V _{NO} = 4.5 V, or V _{COM} = 4.5 V, V _{NO} = 1 V,	Switch OFF, See Figure 14	25°C Full	5.5 V	-0.5 -5	0.01	0.5	nA
NO		V _{NO} = 1 V, V _{COM} = 1 V, or	Switch ON,	25°C	5.51/	-1	0.01	1	
ON leakage current	INO(ON)	V _{NO} = 4.5 V, V _{COM} = 4.5 V, or V _{NO} = 1 V, 4.5 V, V _{COM} = Open,	See Figure 15	Full	5.5 V	-10		10	nA
COM ON leakage	ICOM(ON)	V _{COM} = 1 V, V _{NO} = 1 V, or V _{COM} = 4.5 V, V _{NO} = 4.5 V,	Switch ON,	25°C	5.5 V	-1	0.01	1	nA
current	"COIVI(ON)	or VCOM = 1 V, 4.5 V, V _{NO} = Open,	See Figure 15	Full	0.0 v	-10		10	10.0
Digital Control Inp	out (IN)								
Input logic high	VIH			Full		2.4		5.5	V
Input logic low	V _{IL}			Full		0		8.0	V
Input leakage current	I _{IH} , I _{IL}	V _I = V ₊ or 0		25°C Full	5.5 V	-0.5 -5	0.01	0.5	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



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Electrical Characteristics for 5-V Supply⁽¹⁾ (continued) $V_+ = 4.5 \text{ V to } 5.5 \text{ V}, T_A = -40 ^{\circ}\text{C to } 85 ^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		TA	V ₊	MIN .	TYP	MAX	UNIT
Dynamic						-			
Turn-on time	4	V _{NO} = 3 V,	C _I = 35 pF,		5 V		12	17	20
Turr-on time	tON	$R_L = 300 \Omega$,	See Figure 17	Full	4.5 V to 5.5 V			19	ns
Turn-off time	torr	$V_{COM} = 3 V$	$C_L = 35 pF$,	25°C	5 V		9	14	ns
Tarri on time	tOFF	$R_L = 300 \Omega$,	See Figure 17	Full	4.5 V to 5.5 V			17	115
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF,	See Figure 20	25°C	5 V		2	5	pC
NO OFF capacitance	C _{NO(OFF)}	$V_{NO} = V_{+} \text{ or GND},$ f = 1 MHz,	Switch OFF, See Figure 16	25°C	5 V		6.5		pF
COM OFF capacitance	CCOM(OFF)	V _{COM} = V ₊ or GND, f = 1 MHz,	Switch OFF, See Figure 16	25°C	5 V		6.5		pF
NO ON capacitance	C _{NO(ON))}	V _{NO} = V ₊ or GND, f = 1 MHz,	Switch ON, See Figure 16	25°C	5 V		13		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, f = 1 MHz,	Switch ON, See Figure 16	25°C	5 V		13		pF
Digital input capacitance	CI	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	5 V		3		pF
Bandwidth	BW	$R_L = 50 \Omega$, Signal = 0 dBm,	Switch ON, See Figure 18	25°C	5 V		450		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, $C_L = 5 pF$, $V_{NO} = 1 V_{RMS}$, $f = 1 MHz$,	Switch OFF, See Figure 19	25°C	5 V		-85		dB
Total harmonic distortion	THD	$R_L = 600 \Omega$, $C_L = 50 pF$, $V_{SOURCE} = 5 V_{p-p}$,	f = 20 Hz to 20 kHz, See Figure 21	25°C	5 V		0.04		%
Supply	•	•		•	•	•			
Positive supply		V V OND	Outlieb ON as OFF	25°C	5.5.1/		0.01	0.25	Δ.
current	l ₊	$V_I = V_+ \text{ or GND},$	Switch ON or OFF		5.5 V			0.5	μΑ

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



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Electrical Characteristics for 3-V Supply⁽¹⁾ $V_+ = 2.7 \text{ V}$ to 3.6 V, $T_A = -40 ^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	TA	٧+	MIN	TYP	MAX	UNIT	
Analog Switch				-		-			
Analog signal range	V _{COM} , V _{NO}					0		V ₊	>
ON-state	r _{on}	V _{NO} = 1.5 V,	Switch ON,	25°C	2.7 V		9.5	16	Ω
resistance	.011	ICOM = 10 mA,	See Figure 13	Full				20	
ON-state resistance	r (11 1)	V _{NO} = 1.5 V, 2.5 V,	Switch ON,	25°C	2.7 V		1.8	6	Ω
flatness	ron(flat)	I _{COM} = 10 mA,	See Figure 13	Full	2.7 V			7	52
NO OFF lealers		V _{NO} = 1 V, V _{COM} = 3 V,	Switch OFF,	25°C	0.01/	-0.5	0.01	0.5	
OFF leakage current	INO(OFF)	$V_{NO} = 3 \text{ V}, V_{COM} = 1 \text{ V},$	See Figure 14	Full	3.6 V	-5		5	nA
COM		V _{COM} = 1 V, V _{NO} = 3 V,	Switch OFF,	25°C	3.6 V	-0.5	0.01	0.5	
OFF leakage current	ICOM(OFF)	$V_{COM} = 3 \text{ V}, V_{NO} = 1 \text{ V},$	See Figure 14	Full		-5		5	nA
NO ON lookees		V _{NO} = 1 V, V _{COM} = 1 V, or	Switch ON,	25°C		-1	0.01	1	- ^
ON leakage current	INO(ON)	V _{NO} = 3 V, V _{COM} = 3 V, or V _{NO} = 1 V, 3 V, V _{COM} = Open,	See Figure 15	Full	3.6 V	-10		10	nA
СОМ		V _{COM} = 1 V, V _{NO} = 1 V,	Switch ON,	25°C		-1	0.01	1	
ON leakage current	ICOM(ON)	$V_{COM} = 3 \text{ V}, V_{NO} = 3 \text{ V},$ or $V_{COM} = 1 \text{ V}, 3 \text{ V}, V_{NO} = \text{Open},$	See Figure 15	Full	3.6 V	-10		10	nA
Digital Control Inj	out (IN)	,							1
Input logic high	VIH			Full		2		5.5	V
Input logic low	VIL			Full		0		0.8	V
Input leakage current	I _{IH} , I _{IL}	V _I = V ₊ or 0		25°C Full	3.6 V	-0.5 -5	0.01	0.5 5	nA

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum



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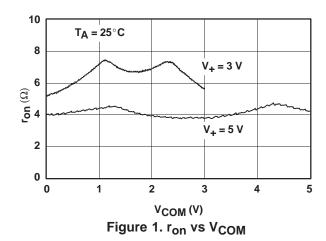
Electrical Characteristics for 3-V Supply⁽¹⁾ (continued) $V_+ = 2.7 \text{ V to } 3.6 \text{ V}, T_A = -40 ^{\circ}\text{C to } 85 ^{\circ}\text{C}$ (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		TA	٧+	MIN	TYP	MAX	UNIT
Dynamic									
Turn-on time	$V_{NO} = 2 V$, $C_{I} = 35 pF$,		C _L = 35 pF,	25°C	3 V		20	30	
rum-on time	tON	$R_L = 300 \Omega$,	See Figure 17	Full	2.7 V to 3.6 V			35	ns
Turn-off time	to ==	V _{NO} = 2 V,	$C_L = 35 pF$,	25°C	3 V		15	25	20
Turri on time	tOFF	$R_L = 300 \Omega$,	See Figure 17	Full	2.7 V to 3.6 V			30	ns
Charge injection	QC	V _{GEN} = 0, R _{GEN} = 0, C _L = 1 nF,	See Figure 20	25°C	3 V		1	4	рС
NO OFF capacitance	C _{NO(OFF)}	V _{NO} = 0, f = 1 MHz,	Switch OFF, See Figure 16	25°C	3 V		6.5		pF
COM OFF capacitance	C _{COM} (OFF)	V _{COM} = 0, f = 1 MHz,	Switch OFF, See Figure 16	25°C	3 V		6.5		pF
NO ON capacitance	C _{NO(ON)}	V _{NO} = 0, f = 1 MHz,	Switch ON, See Figure 16	25°C	3 V		13		pF
COM ON capacitance	C _{COM} (ON)	V _{COM} = 0, f = 1 MHz,	Switch ON, See Figure 16	25°C	3 V		13		pF
Digital input capacitance	Cl	$V_I = V_+$ or GND,	See Figure 16	25°C	3 V		3		pF
Bandwidth	BW	$R_L = 50 \Omega$, Signal = 0 dBm,	Switch ON, See Figure 18	25°C	3 V		450		MHz
OFF isolation	O _{ISO}	V _{NO} = 1 V _{RMS} , f = 1 MHz, C _L = 5 pF,	Switch OFF, See Figure 19	25°C	3 V		-85		dB
Total harmonic distortion	THD	$R_L = 600 \Omega$, $C_L = 50 pF$, $V_{SOURCE} = 3 V_{p-p}$,	f = 20 Hz to 20 kHz, See Figure 21	25°C	3 V		0.09		%
Supply				•					
Positive supply current	l ₊	$V_I = V_+$ or GND,	Switch ON or OFF	25°C Full	3.6 V		0.01	0.25	μА

⁽¹⁾ The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum

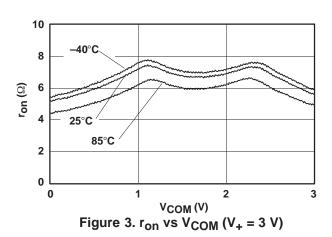


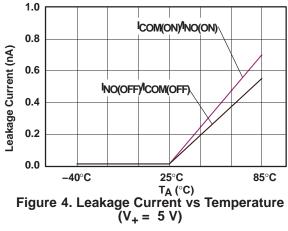
TYPICAL PERFORMANCE

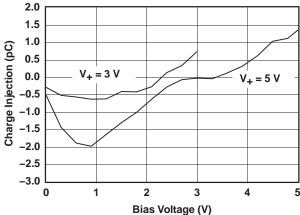


6 85°C 25°C ری) uo_J –40°C 2 0 4 0 2 5

VCOM (V) Figure 2. r_{on} vs V_{COM} ($V_{+} = 5 V$)







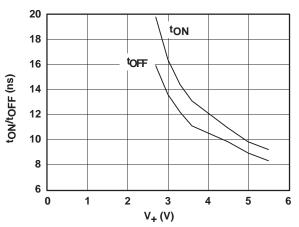


Figure 5. Charge-Injection (Q_C) vs V_{COM}

Figure 6. t_{ON} and t_{OFF} vs Supply Voltage



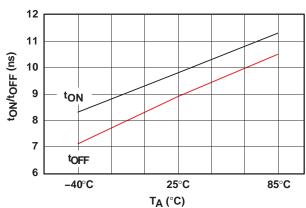


Figure 7. t_{ON} and t_{OFF} vs Temperature (V₊ = 5 V)

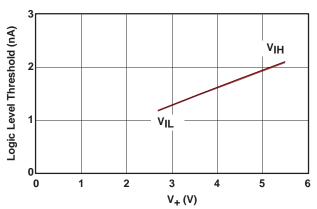


Figure 8. Logic-Level Threshold vs V₊

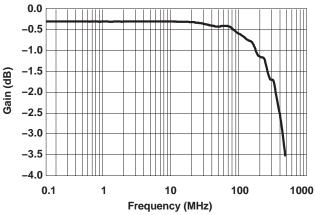


Figure 9. Bandwidth (Gain vs Frequency) $(V_+ = 5 V)$

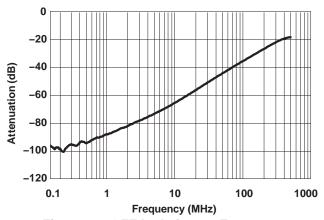


Figure 10. OFF Isolation vs Frequency

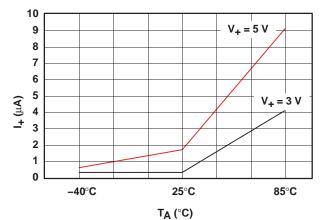


Figure 11. Power-Supply Current vs Temperature

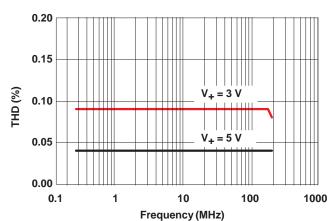


Figure 12. Total Harmonic Distortion vs Frequency



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PIN DESCRIPTION

PIN NUMBER	NAME	DESCRIPTION
1	IN	Digital control pin to connect COM to NO
2	COM	Common
3	GND	Digital ground
4	NO	Normally open
5	V ₊	Power supply

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION
VCOM	Voltage at COM
V _{NO}	Voltage at NO
r _{on}	Resistance between COM and NO ports when the channel is ON
ron(flat)	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions
I _{NO(OFF)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state
I _{NO(ON)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) open
ICOM(OFF)	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the OFF state
ICOM(ON)	Leakage current measured at the COM port, with the corresponding channel (COM to NO) in the ON state and the output (NO) open
VIH	Minimum input voltage for logic high for the control input (IN)
V _{IL}	Maximum input voltage for logic low for the control input (IN)
VI	Voltage at the control input (IN)
I _{IH} , I _{IL}	Leakage current measured at the control input (IN)
tON	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning ON.
^t OFF	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog output (COM or NO) signal when the switch is turning OFF.
QC	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NO or COM) output. This is measured in coulomb (C) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_C = C_L \times \Delta V_{COM}$, C_L is the load capacitance, and ΔV_{COM} is the change in analog output voltage.
C _{NO(OFF)}	Capacitance at the NO port when the corresponding channel (NO to COM) is OFF
C _{NO(ON)}	Capacitance at the NO port when the corresponding channel (NO to COM) is ON
C _{COM(OFF)}	Capacitance at the COM port when the corresponding channel (COM to NO) is OFF
C _{COM(ON)}	Capacitance at the COM port when the corresponding channel (COM to NO) is ON
Cl	Capacitance of control input (IN)
O _{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NO to COM) in the OFF state.
BW	Bandwidth of the switch. This is the frequency in which the gain of an ON channel is -3 dB below the DC gain.
THD	Total harmonic distortion describes the signal distortion caused by the analog switch. This is defined as the ratio of root mean square (RMS) value of the second, third, and higher harmonic to the absolute magnitude of the fundamental harmonic.
l ₊	Static power-supply current with the control (IN) pin at V ₊ or GND



PARAMETER MEASUREMENT INFORMATION

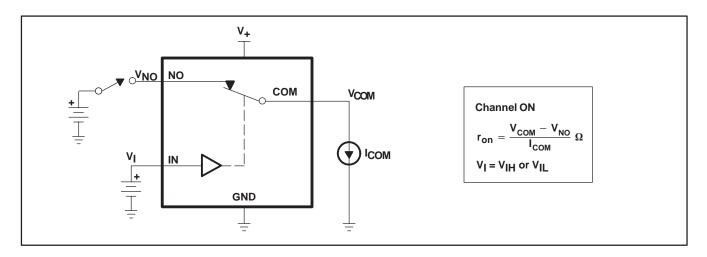


Figure 13. ON-State Resistance (ron)

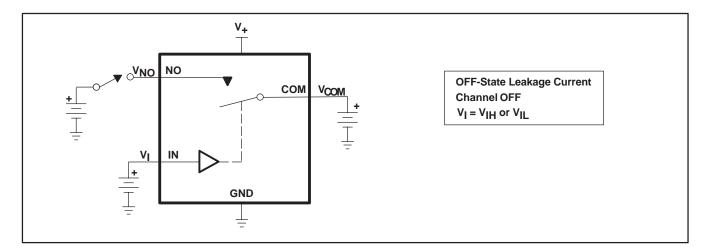


Figure 14. OFF-State Leakage Current ($I_{COM(OFF)}$, $I_{NO(OFF)}$)

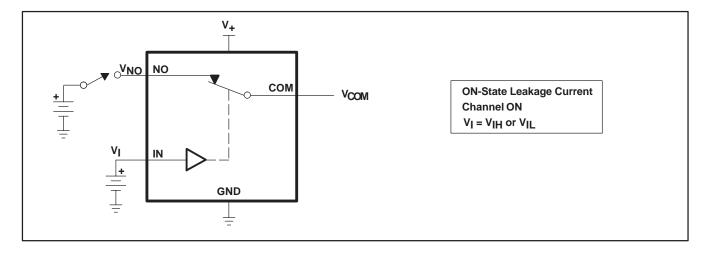


Figure 15. ON-State Leakage Current (I_{COM(ON)}, I_{NO(ON)})

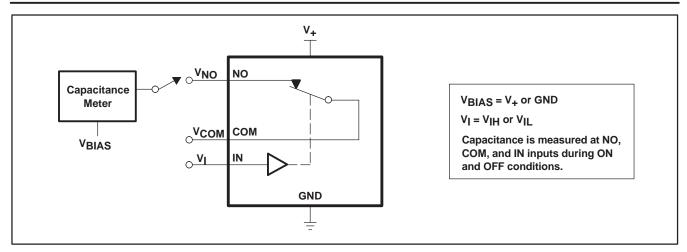
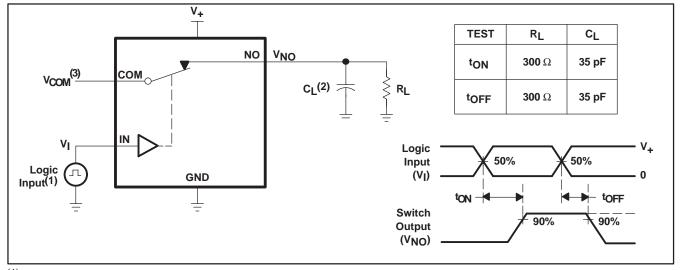


Figure 16. Capacitance (C_I, C_{COM(OFF)}, C_{COM(ON)}, C_{NO(OFF)}, C_{NO(ON)})



- (1) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f < 5$ ns, $t_f < 5$ ns.
- (2) C₁ includes probe and jig capacitance.
- (3) See Electrical Characteristics for V_{COM}.

Figure 17. Turn-On (t_{ON}) and Turn-Off Time (t_{OFF})

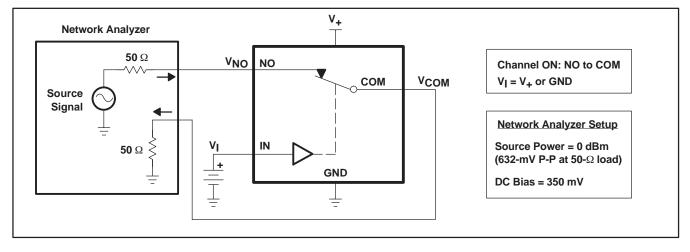


Figure 18. Bandwidth (BW)



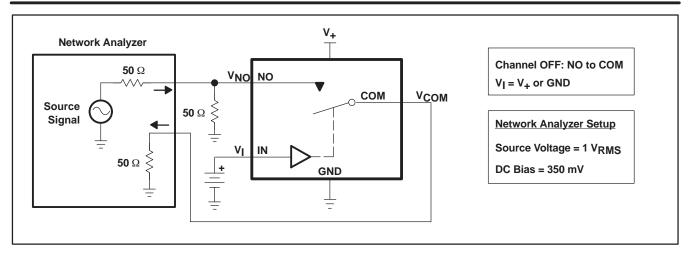
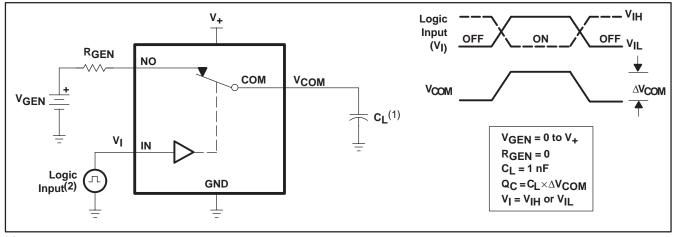
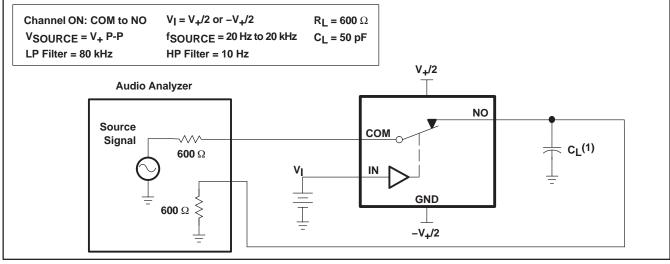


Figure 19. OFF Isolation (O_{ISO})



- (1) C_L includes probe and jig capacitance.
- (2) All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f < 5 \text{ ns}$.

Figure 20. Charge Injection (Q_C)



(2) C_L includes probe and jig capacitance.

Figure 21. Total Harmonic Distortion (THD)



PACKAGE OPTION ADDENDUM

12-Sep-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
TS5A4596DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A4596DBVRE4	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A4596DCKR	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TS5A4596DCKRE4	ACTIVE	SC70	DCK	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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